NSN 5961-00-419-5365

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-419-5365 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** Ea-6b prowler aircraft. Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-76 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Precious Material And Location:** Terminal surfaces gold **Precious Material: Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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